



JIEJIE MICROELECTRONICS CO., LTD.

JST16X-800BW



JieJie Microelectronics Co., Ltd.

Peak pulse voltage
($T_j=25$; non-repetitive, off-state; FIG.7)

V_{pp}

4

kV

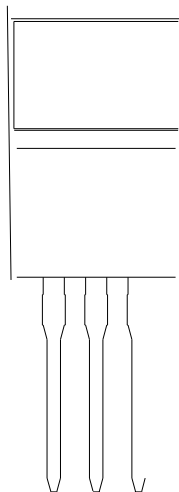
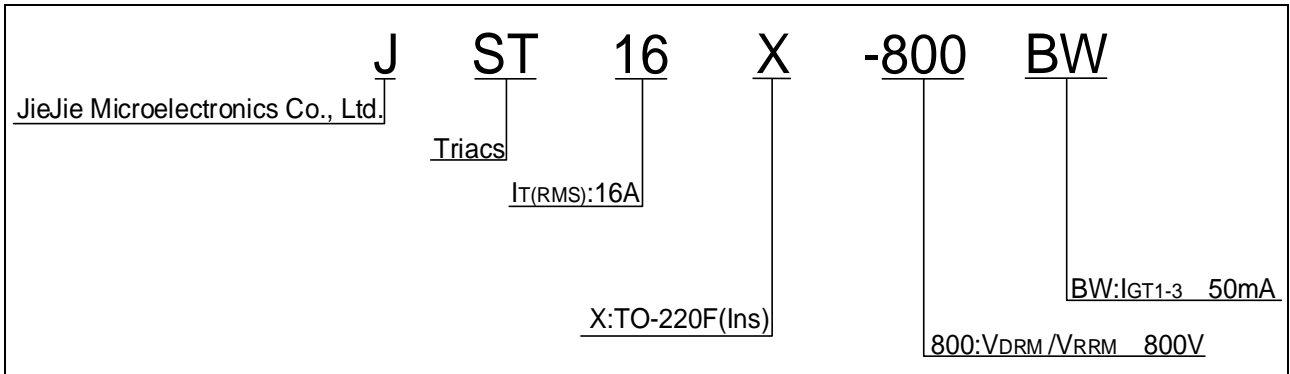


FIG.1: Maximum power dissipation versus RMS on-state current

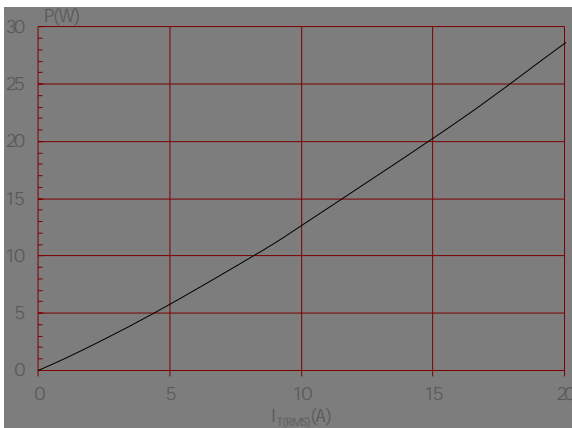


FIG.2: RMS on-state current versus case temperature

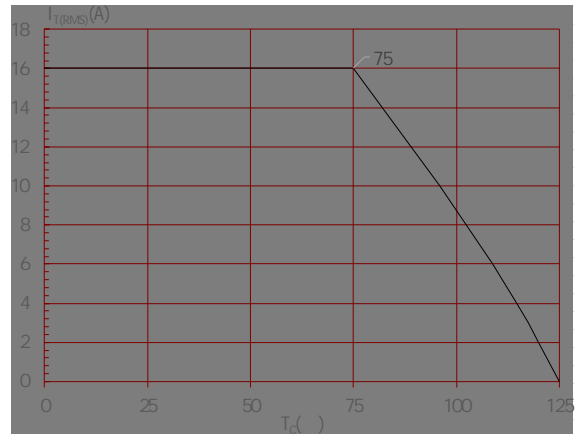


FIG.3: Surge peak on-state current versus number of cycles

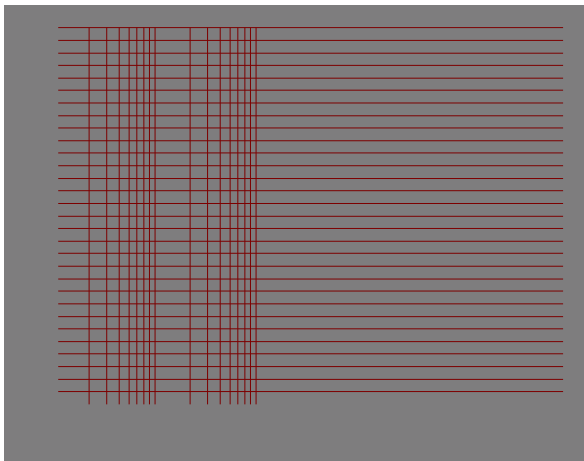


FIG.4: On-state characteristics



Order code	Voltage V_{DRM}/V_{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
		- -			
JST16X-800BW	800	50	TO-220F(Ins)	50	Tube

Document Revision History

Date	Revision	Changes
Apr.10, 2023	A.1.0	Last updated
Oct.15, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

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